TOSHIBA Transistor Silicon PNP Epitaxial Type

2SA2061

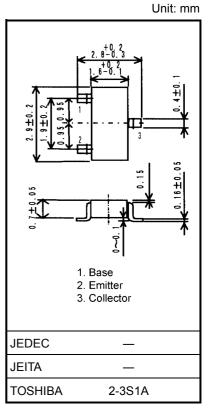
High-Speed Switching Applications DC-DC Converter Applications Strobe Applications

- High DC current gain: $h_{\rm FE}$ = 200 to 500 (I_C = 0.5 A)
- Low collector-emitter saturation voltage: $V_{CE (sat)} = -0.19 \text{ V (max)}$
- High-speed switching: $t_f = 40 \text{ ns (typ.)}$

Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	-20	٧	
Collector-emitter voltage		V _{CEO}	-20	٧	
Emitter-base voltage		V _{EBO}	-7	V	
Collector current	DC	Ic	- 2.5	Α	
	Pulse	I _{CP}	-4.0		
Base current		I _B	-250	mA	
Collector power dissipation	t = 10 s	PC	1000	mW	
	DC	(Note)	625		
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	−55 to 150	°C	

Note: Mounted on FR4 board (glass epoxy, 1.6 mm thick, Cu area: 645 mm²)



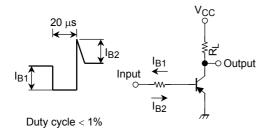
Weight: 0.01 g (typ.)

Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I _{CBO}	V _{CB} = -20 V, I _E = 0	_	_	-100	nA
Emitter cut-off current		I _{EBO}	V _{EB} = -7 V, I _C = 0	_	_	-100	nA
Collector-emitter breakdown voltage		V (BR) CEO	$I_C = -10 \text{ mA}, I_B = 0$	-20	_	_	V
DC current gain		h _{FE} (1)	$V_{CE} = -2 \text{ V}, I_{C} = 0.5 \text{ A}$	200	_	500	
		h _{FE} (2)	V _{CE} = -2 V, I _C = -1.6 A	100	_	_	
Collector-emitter saturation voltage		V _{CE} (sat)	I _C = -1.6 A, I _B = -53 mA	_	_	-0.19	V
Base-emitter saturation voltage		V _{BE (sat)}	I _C = -1.6 A, I _B = -53 mA	_	_	-1.10	V
Collector output capacitance		C _{ob}	V _{CB} = −10 V, I _E = 0, f = 1 MHz	_	28	_	pF
Switching time	Rise time	t _r	See Figure 1 circuit diagram.	_	70	_	ns
	Storage time	t _{stg}	$V_{CC} \approx -12 \text{ V}, R_L = 7.5 \Omega$	_	150	_	
	Fall time	t _f	$-I_{B1} = I_{B2} = -53 \text{ mA}$	_	40	_	

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Marking



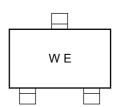
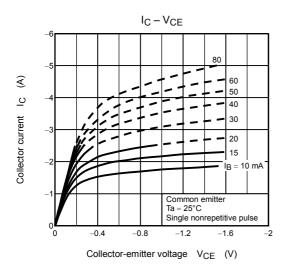
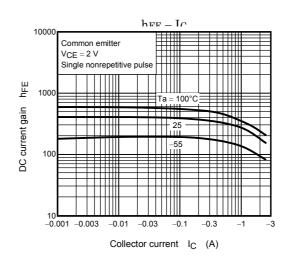
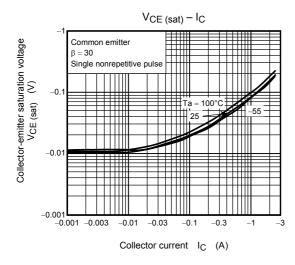
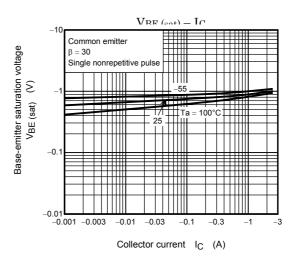


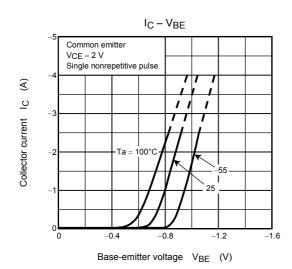
Figure 1 Switching Time Test Circuit & Timing Chart

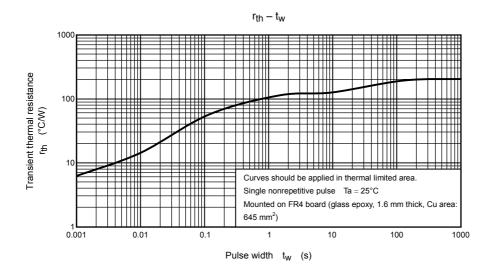


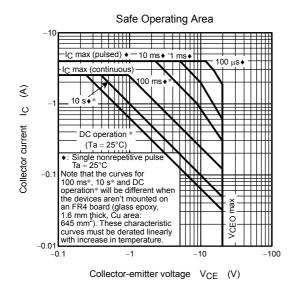












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